

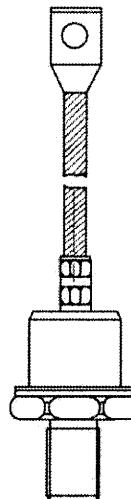
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150KS(R)20

Standard Recovery Diodes



FEATURES

- High surge current capability
- Stud cathode and stud anode version
- Designed and qualified for industrial and consumer level
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Battery charges
- Converters
- Power supplies
- Machine tool controls

Case Style DO-8

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	CONDITIONS		VALUE	UNIT	
V_{RRM}	Repetitive Peak Reverse Voltage			200	V	
$I_{F(AV)}$	Average Forward Current	$T_c=125^\circ\text{C}$, 180° conduction, half sine wave		150	A	
$I_{F(RMS)}$	RMS forward current	$T_c=110^\circ\text{C}$		235	A	
I_{FSM}	Surge Forward Current	$t=10\text{ms}$	No voltage reapplied	3000	A	
		$t=8.3\text{ms}$		3140		
I^2t	I^2t for fusing	$t=10\text{ms}$	No voltage reapplied	45	KA_2s	
		$t=8.3\text{ms}$		41		
T_J	Junction Temperature			-40~180	°C	
T_{stg}	Storage Temperature			-40~180	°C	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th j-c}$	Thermal Resistance, Junction to Case	0.30	°C/W

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ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	MAX	UNIT
V_{FM}	Forward Voltage drop	$I_F = 600A, T_J = 25^\circ C, t_p = 10ms$	1.47	V
I_{RRM}	Maximum Instantaneous Reverse Current	$V_R = V_{RWM}, T_C = 175^\circ C$	35	mA

PACKAGE OUTLINE

Dimensions in mm (1mm = 0.0394")

